

# **GBJ50005 thru GBJ5010**

# 50.0 A Single-Phase Silicon Bridge Rectifier Rectifier Reverse Voltage 50 to 1000V

## **Features**

- Ideal for printed circuit board mounting
- This series is UL listed under the Recognized Component Index, file number E484648
- The plastic material used carries Underwriters Laboratory flammability recognition 94V-0
- Built-in printed circuit board stand-offs
- High case dielectric strength
- High temperature soldering guaranteed 260°C/5 seconds at 5 lbs (2.3kg) tension

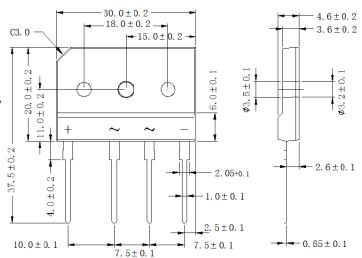
### **Mechanical Data**

Case: Reliable low cost construction utilizing

molded plastic technique

Terminals: Plated leads solderable per MIL-STD-202,

Method 208 Mounting Position: Any



Dimensions in inches and (milimeters)

## **Maximum Ratings & Thermal Characteristics**

Rating at 25°C ambient temperature unless otherwise specified, Resistive or Inductive load, 60 Hz. For Capacitive load derate current by 20%.

Parameter	Symbol	GBJ 50005	GBJ 5001	GBJ 5002	GBJ 5004	GBJ 5006	GBJ 5008	GBJ 5010	unit		
Maximum repetitive peak reverse voltage	VRRM	50	100	200	400	600	800	1000	V		
Maximum RMS bridge input voltage	VRMS	35	70	140	280	420	560	700	V		
Maximum DC blocking voltage	VDC	50	100	200	400	600	800	1000	V		
Maximum Average Forward (with heatsink Note2	num Average Forward (with heatsink Note2) <sub>IF(AV)</sub>				50.0						
Rectified Current @ T C=100°C	50.0										
Peak forward surge current single sine-wave superimposed on rated load (JEDEC Method)	IFSM	500							А		
Operating junction and storage temperature range	TJ, TSTG	-55 to + 150							ဗ		

## **Electrical Characteristics**

Rating at 25°C ambient temperature unless otherwise specified. Resistive or Inductive load, 60Hz. For Capacitive load derate by 20 %.

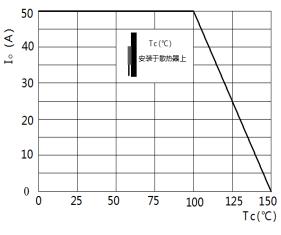
Parameter	Symbol	GBJ 50005	GBJ 5001	GBJ 5002	GBJ 5004	GBJ 5006	GBJ 5008	GBJ 5010	Unit
Maximum instantaneous forward voltage drop perleg at 25.0A	VF	1.1							V
Maximum DC reverse current at rated TA =25°C DC blocking voltage per element TA =125°C	IR	10 500						μΑ	

Notes: (1)Thermal resistance from Junction to Ambemt on P.C.board mounting.

(2). Device mounted on 300mm\*300mm\*1.6mm cu plate heatsink.

## Rating and Characteristic Curves (TA=25°C Unless otherwise noted) GBJ50005 thru GBJ5010

FIG.1-FORWARD CURRENT DERATING CURVE

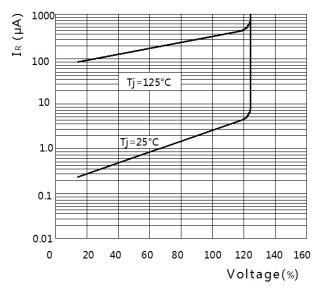


IFSM (A) 500 450 400 350 300 250 200 150

100 50 0 FIG.2-MAXMUN NON-REPETITIVE SURGE CURRENT

CASE TEMPERATURE, ℃

FIG.3-TYPICAL REVERSE



#### FIG.4-TYPICAL FORWARD CHARACTERISTICS

频率为50HZ的脉冲个数

20 50 100 Time (Cycless)

